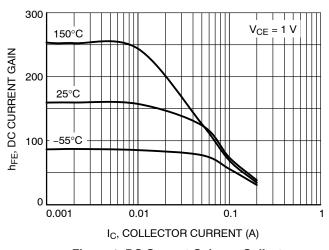
# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteris	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector - Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)CEO</sub>	65 45 30	- - -	- - -	V
Collector – Emitter Breakdown Voltage ( $I_C = 10 \mu A, V_{EB} = 0$ )	BC846A, B, C BC847A, B, C BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)</sub> CES	80 50 30	- - -	- - -	V
Collector – Base Breakdown Voltage ( $I_C = 10 \mu A$ )	V <sub>(BR)CBO</sub>	80 50 30	- - -	- - -	V	
Emitter – Base Breakdown Voltage ( $I_E = 1.0 \mu A$ )	BC846A, B, C BC847A, B, C, BC850B, C BC848A, B, C, BC849B, C	V <sub>(BR)EBO</sub>	6.0 6.0 5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = 30 V) (V <sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)		I <sub>CBO</sub>	- -	- -	15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V)	BC846A, BC847A, BC848A BC846B, BC847B, BC848B BC846C, BC847C, BC848C	h <sub>FE</sub>	- - -	90 150 270	- - -	-
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC846A, BC847A, BC848A BC846B, BC847B, BC848B, BC849B, BC850B		110 200	180 290	220 450	
BC846C, B0	C847C, BC848C, BC849C, BC850C		420	520	800	
Collector – Emitter Saturation Voltage ( $I_C = (I_C = I_C)$	10 mA, I <sub>B</sub> = 0.5 mA) 100 mA, I <sub>B</sub> = 5.0 mA)	V <sub>CE(sat)</sub>	- -	- -	0.25 0.6	V
Base – Emitter Saturation Voltage ( $I_C = 10 \text{ r}$ ) ( $I_C = 100 \text{ r}$ )	mA, I <sub>B</sub> = 0.5 mA) mA, I <sub>B</sub> = 5.0 mA)	V <sub>BE(sat)</sub>	- -	0.7 0.9	- -	V
Base – Emitter Voltage ( $I_C$ = 2.0 mA, $V_{CE}$ = ( $I_C$ = 10 mA, $V_{CE}$ = 5	V <sub>BE(on)</sub>	580 -	660 -	700 770	mV	
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz	f <sub>T</sub>	100	_	-	MHz	
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MI	C <sub>obo</sub>	-	-	4.5	pF	
Noise Figure ( $I_C$ = 0.2 mA, $V_{CE}$ = 5.0 Vdc, $R_S$ = 2.0 k $\Omega$ , BC846 f = 1.0 kHz, BW = 200 Hz) BC849	NF	_ _	- -	10 4.0	dB	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### BC846A, BC847A, BC848A, SBC846A



300 150°C VCE = 5 V VCE = 5 V 200 25°C 100 -55°C 0 0.001 0.01 1C, COLLECTOR CURRENT (A)

Figure 1. DC Current Gain vs. Collector Current

Figure 2. DC Current Gain vs. Collector Current

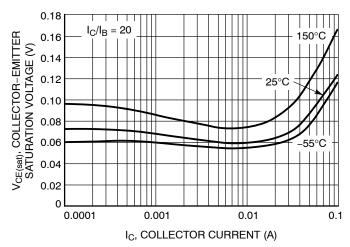


Figure 3. Collector Emitter Saturation Voltage vs. Collector Current

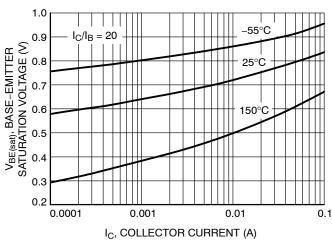


Figure 4. Base Emitter Saturation Voltage vs.
Collector Current

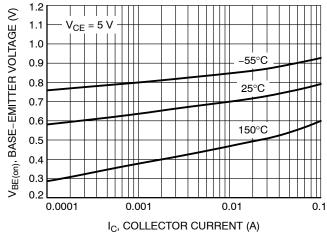
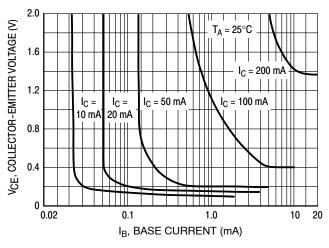


Figure 5. Base Emitter Voltage vs. Collector Current

## BC846A, BC847A, BC848A, SBC846A



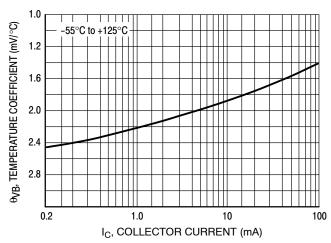


Figure 6. Collector Saturation Region

Figure 7. Base-Emitter Temperature Coefficient

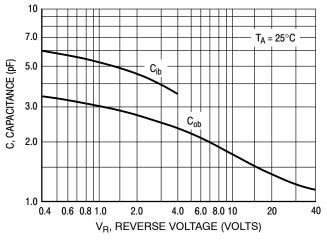


Figure 8. Capacitances

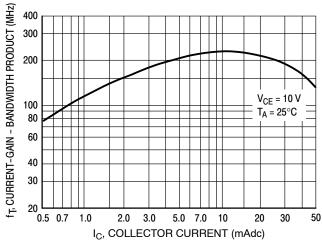


Figure 9. Current-Gain - Bandwidth Product

#### BC846B, SBC846B

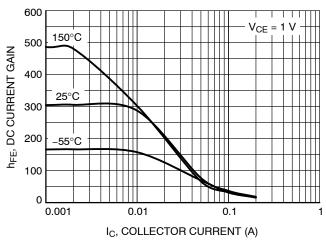


Figure 10. DC Current Gain vs. Collector Current

Figure 11. DC Current Gain vs. Collector Current

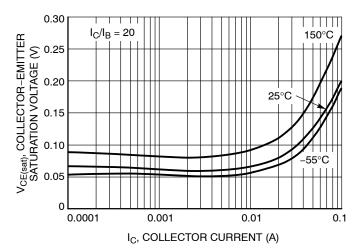


Figure 12. Collector Emitter Saturation Voltage vs. Collector Current

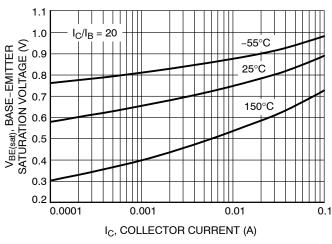


Figure 13. Base Emitter Saturation Voltage vs. Collector Current

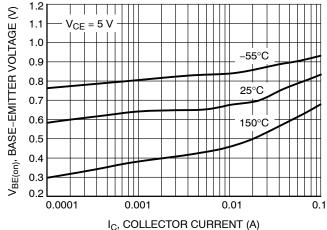
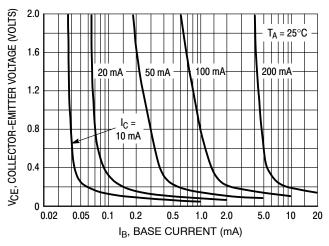


Figure 14. Base Emitter Voltage vs. Collector Current

## BC846B, SBC846B



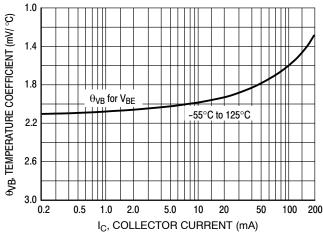


Figure 15. Collector Saturation Region

Figure 16. Base-Emitter Temperature Coefficient

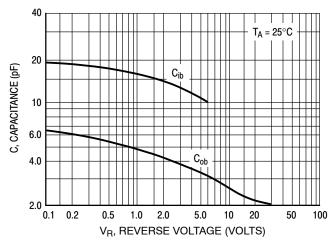


Figure 17. Capacitance

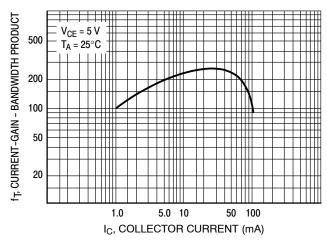
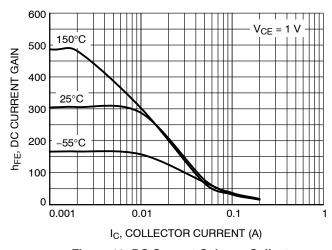


Figure 18. Current-Gain - Bandwidth Product

## BC847B, BC848B, BC849B, BC850B, SBC847B, SBC848B



600  $V_{CE} = 5 V$ 150°C 500 h<sub>FE</sub>, DC CURRENT GAIN 400 25°C 300 200 -55°C 100 0 0.001 0.01 0.1 I<sub>C</sub>, COLLECTOR CURRENT (A)

Figure 19. DC Current Gain vs. Collector Current

Figure 20. DC Current Gain vs. Collector Current

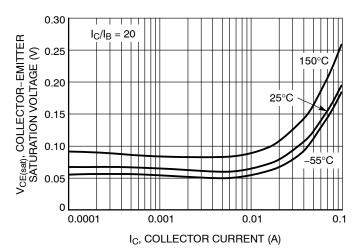


Figure 21. Collector Emitter Saturation Voltage vs. Collector Current

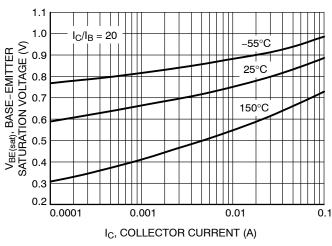


Figure 22. Base Emitter Saturation Voltage vs. Collector Current

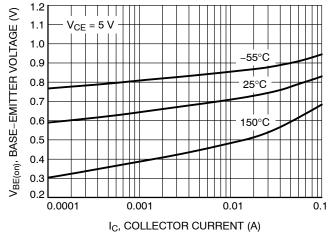
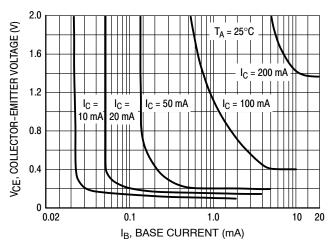


Figure 23. Base Emitter Voltage vs. Collector Current

# BC847B, BC848B, BC849B, BC850B, SBC846B, SBC847B, SBC848B



1.0 --55°C to +125°C 1.2 1.6 2.0 2.4 2.8 0.2 1.0 1.0 10 100 I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 24. Collector Saturation Region

Figure 25. Base–Emitter Temperature Coefficient

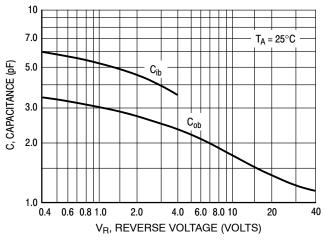


Figure 26. Capacitances

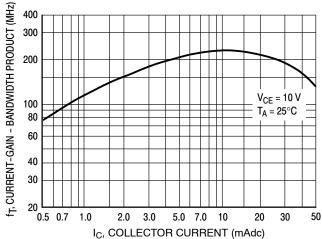
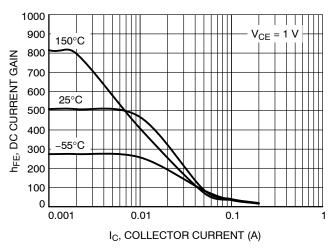


Figure 27. Current-Gain - Bandwidth Product

## BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C



1000 900 150°C  $V_{CE}$ 800 hFE, DC CURRENT GAIN 700 600 25°C 500 400 -55°C 300 200 100 0.001 0.01 0.1 IC, COLLECTOR CURRENT (A)

Figure 28. DC Current Gain vs. Collector Current

Figure 29. DC Current Gain vs. Collector Current

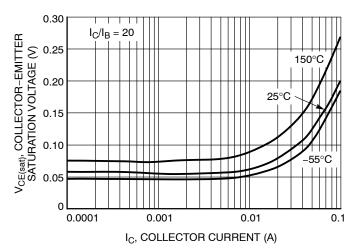


Figure 30. Collector Emitter Saturation Voltage vs. Collector Current

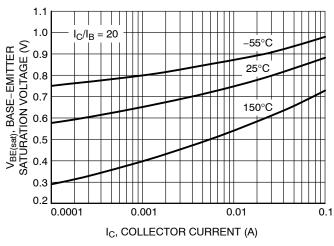


Figure 31. Base Emitter Saturation Voltage vs. Collector Current

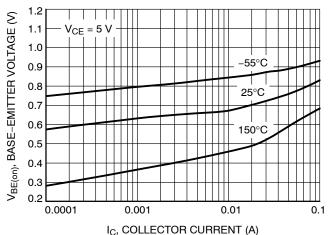
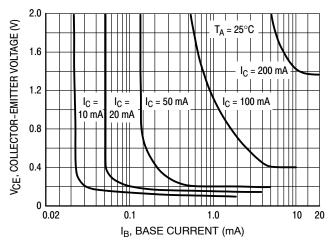


Figure 32. Base Emitter Voltage vs. Collector Current

# BC846C, BC847C, BC848C, BC849C, BC850C, SBC847C



1.0 --55°C to +125°C 1.2 1.6 2.0 2.4 2.8 0.2 1.0 1.0 10 100 100 100

Figure 33. Collector Saturation Region

Figure 34. Base–Emitter Temperature Coefficient

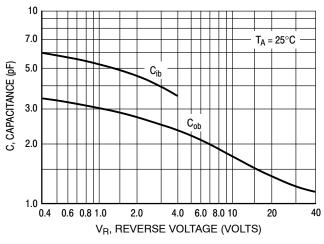


Figure 35. Capacitances

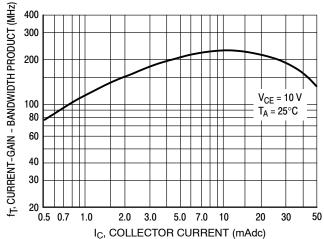


Figure 36. Current-Gain - Bandwidth Product

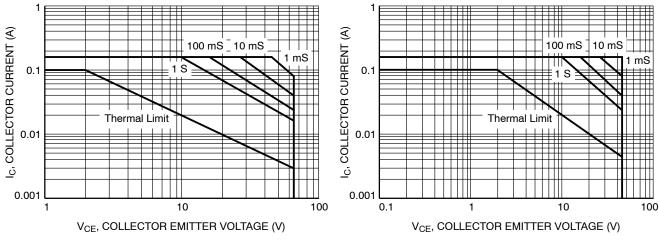


Figure 37. Safe Operating Area for BC846A, BC846B, BC846C

Figure 38. Safe Operating Area for BC847A, BC847B, BC847C, BC850B, BC850C

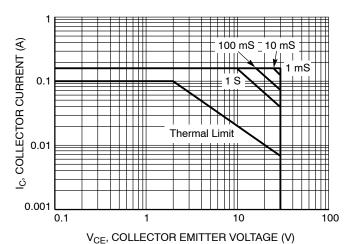


Figure 39. Safe Operating Area for BC848A, BC848B, BC848C, BC849B, BC849C

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
BC846ALT1G			
SBC846ALT1G*	1A		3,000 / Tape & Reel
BC846ALT3G			10,000 / Tape & Reel
BC846BLT1G			0.000 (7
SBC846BLT1G*			3,000 / Tape & Reel
BC846BLT3G	1B		10 000 /T
SBC846BLT3G*			10,000 / Tape & Reel
BC846CLT1G	3C		3,000 / Tape & Reel
BC847ALT1G			3,000 / Tape & Reel
BC847ALT3G	1E		10,000 / Tape & Reel
BC847BLT1G			
SBC847BLT1G*			3,000 / Tape & Reel
BC847BLT3G	1F		
NSVBC847BLT3G*			10,000 / Tape & Reel
BC847CLT1G		SOT-23 (Pb-Free)	
SBC847CLT1G*	1G		3,000 / Tape & Reel
BC847CLT3G			10,000 / Tape & Reel
BC848ALT1G	1J	(. 2	3,000 / Tape & Reel
BC848BLT1G			
SBC848BLT1G*	1K		3,000 / Tape & Reel
BC848BLT3G			10,000 / Tape & Reel
BC848CLT1G			0.000 (T 0. P I
NSVBC848CLT1G*	1L		3,000 / Tape & Reel
BC848CLT3G			10,000 / Tape & Reel
BC849BLT1G			0.000 / Table 9 Park
NSVBC849BLT1G*	2B		3,000 / Tape & Reel
BC849BLT3G			10,000 / Tape & Reel
BC849CLT1G			3,000 / Tape & Reel
BC849CLT3G	2C		10,000 / Tape & Reel
BC850BLT1G	oF.		
NSVBC850BLT1G*	2F		2 000 / Terra 9 Daal
BC850CLT1G	00	1	3,000 / Tape & Reel
NSVBC850CLT1G*	2G		

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

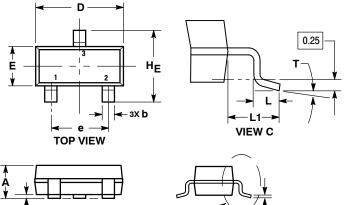
<sup>\*</sup>S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



SOT-23 (TO-236) CASE 318-08 **ISSUE AS** 

**DATE 30 JAN 2018** 

# SCALE 4:1



SEE VIEW C

**END VIEW** 

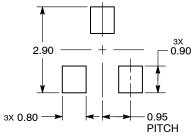
# NOTES:

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
  MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS.

	M	ILLIMETE	RS			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.00 1.11		0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.35 0.54		0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	O٥		100	O٥		10°

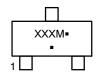
#### **RECOMMENDED SOLDERING FOOTPRINT**

SIDE VIEW



DIMENSIONS: MILLIMETERS

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE
STVI F a	OTV/1 F 40:	OT/1 E 44	OT (1 5 40)

SOT-23 (TO-236)

STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
<ol><li>ANODE</li></ol>	<ol><li>SOURCE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	2. DRAIN	2. GATE
<ol><li>CATHODE</li></ol>	<ol><li>GATE</li></ol>	<ol><li>CATHODE-ANODE</li></ol>	<ol><li>ANODE</li></ol>	<ol><li>GATE</li></ol>	<ol><li>ANODE</li></ol>

STYLE 1	5:	STYLE 1	6:	STYLE 1	7:	STYLE 1	8:	STYLE 1	19:	STYLE 2	20:
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	NO CONNECTION	PIN 1.	NO CONNECTION	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	CATHODE	2.	CATHODE	2.	ANODE	2.	CATHODE	2.	ANODE	2.	ANODE
3.	ANODE	3.	CATHODE	3.	CATHODE	3.	ANODE	3.	CATHODE-ANODE	3.	GATE

STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	<ol><li>OUTPUT</li></ol>	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3 DRAIN	3 INPUT	3 CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION

2. CATHODE 2.	28: . ANODE 2. ANODE 3. ANODE	
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PAGE 1 OF 1

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Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

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